TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

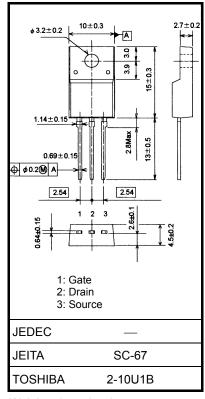
TK18A50D

Switching Regulator Applications

- Low drain-source ON resistance: $RDS(ON) = 0.22 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 8.5 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 500 \ V)$
- Enhancement-mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Characte	ristics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	500	V	
Gate-source voltage		V _{GSS}	±30	V	
Drain current	DC (Note ') I _D	18	А	
	Pulse (Note) I _{DP}	72	A .	
Drain power dissipation	on (Tc = 25°C)	PD	50	W	
Single pulse avalanch	ne energy (Note 2	E _{AS}	533	mJ	
Avalanche current		I _{AR}	18	А	
Repetitive avalanche	energy (Note 3) E _{AR}	5.0	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature	range	T _{stg}	–55 to 150	°C	

Absolute Maximum Ratings (Ta = 25°C)



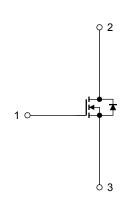
Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	2.5	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W	

Internal Connection



Start of commercial production 2009-01

Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 2.8 mH, R_G = 25 Ω , I_{AR} = 18 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Unit: mm

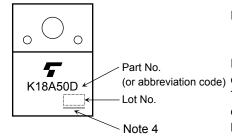
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500		_	V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 9 \text{ A}$		0.22	0.27	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 9 \text{ A}$	2.4	8.5	_	S
Input capacitance		C _{iss}			2600	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		11	_	pF
Output capacitance		C _{oss}			280		
Switching time	Rise time	tr	$V_{GS} = 9 A V_{OUT}$		50		. ns
	Turn-on time	t _{on}			100		
	Fall time	t _f			25	_	
	Turn-off time	t _{off}	Duty \leq 1%, t _w = 10 μ s		150	_	
Total gate charge		Qg			45		
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 18 \text{ A}$	_	28		nC
Gate-drain charge		Q _{gd}	1	_	17		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	18	А
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	72	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 18 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 18 \text{ A}, V_{GS} = 0 \text{ V},$	_	1700	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	26	_	μC

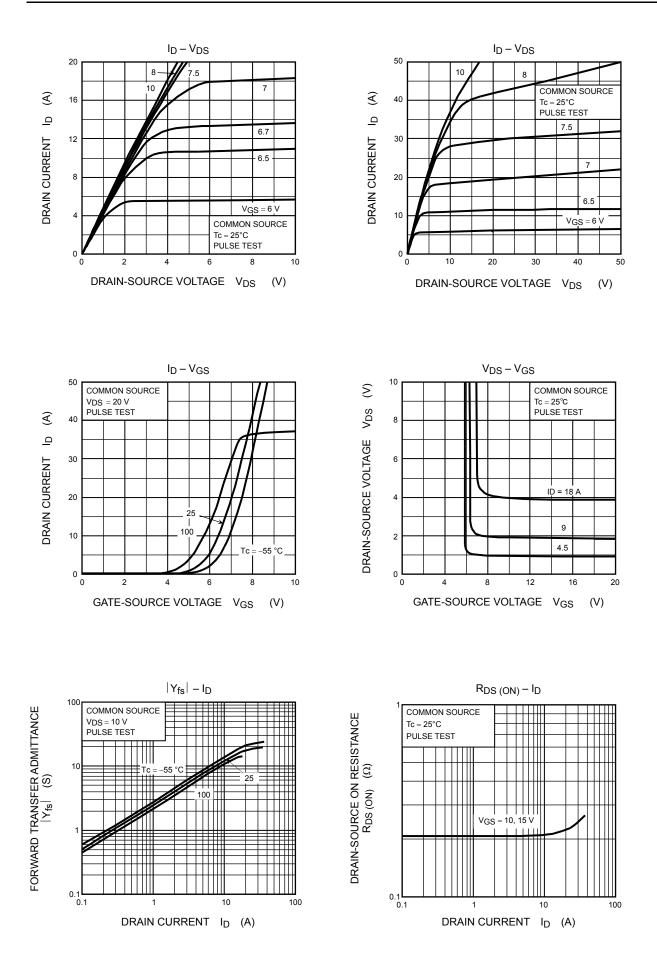
Marking



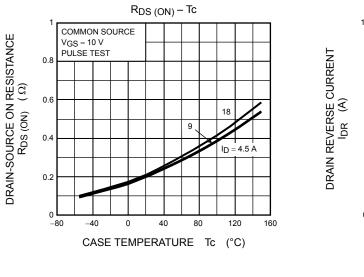
Note 4: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

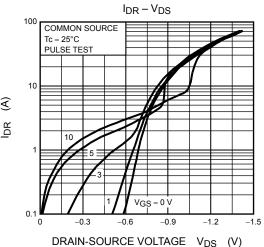
Part No.Please contact your TOSHIBA sales representative for details as to
environmental matters such as the RoHS compatibility of Product.Lot No.The RoHS is Directive 2011/65/EU of the European Parliament and
of the Council of 8 June 2011 on the restriction of the use of certain
hazardous substances in electrical and electronic equipment

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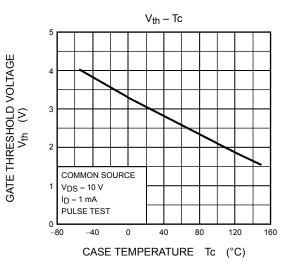


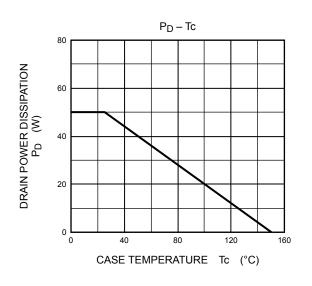
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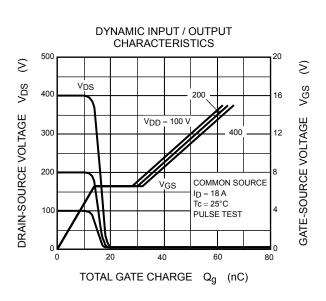


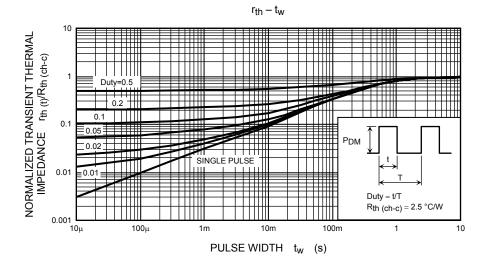


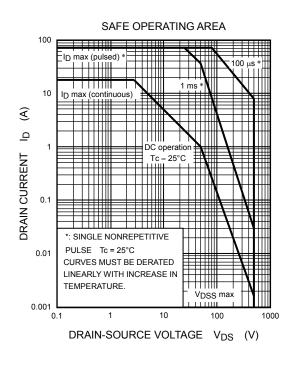
CAPACITANCE - VDS 10000 Ciss $\left| \right|$ (PF) 1000 ပ loss CAPACITANCE 100 10 COMMON SOURCE $V_{GS} = 0 V$ f = 1 MHz $Tc = 25^{\circ}C$ 1 0.1 1 10 100 DRAIN-SOURCE VOLTAGE VDS (V)

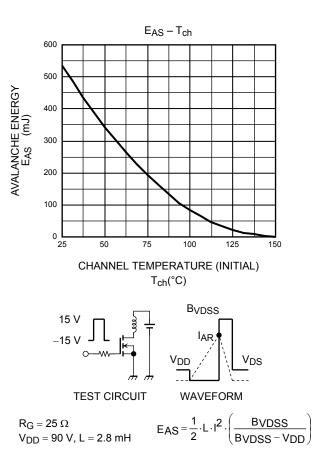












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